National Semiconductor

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LM2524D/LM3524D
Regulating Pulse Width Modulator

General Description

The LM3524D family is an improved version of the industry standard LM3524. It has improved specifications and additional features yet is pin for pin compatible with existing 3524 families. New features reduce the need for additional external circuitry often required in the original version.

The LM3524D has a ±1% precision 5V reference. The current carrying capability of the output drive transistors has been raised to 200 mA while reducing V_{CEsat} and increasing V_{CE} breakdown to 60V. The common mode voltage range of the error-amp has been raised to 5.5V to eliminate the need for a resistive divider from the 5V reference.

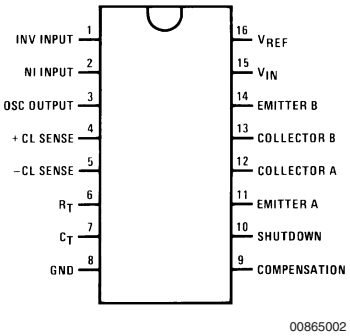
In the LM3524D the circuit bias line has been isolated from the shut-down pin. This prevents the oscillator pulse amplitude and frequency from being disturbed by shut-down. Also at high frequencies (≈300 kHz) the max. duty cycle per output has been improved to 44% compared to 35% max. duty cycle in other 3524s.

In addition, the LM3524D can now be synchronized externally, through pin 3. Also a latch has been added to insure one pulse per period even in noisy environments. The LM3524D includes double pulse suppression logic that insures when a shut-down condition is removed the state of the T-flip-flop will change only after the first clock pulse has arrived. This feature prevents the same output from being pulsed twice in a row, thus reducing the possibility of core saturation in push-pull designs.

Features

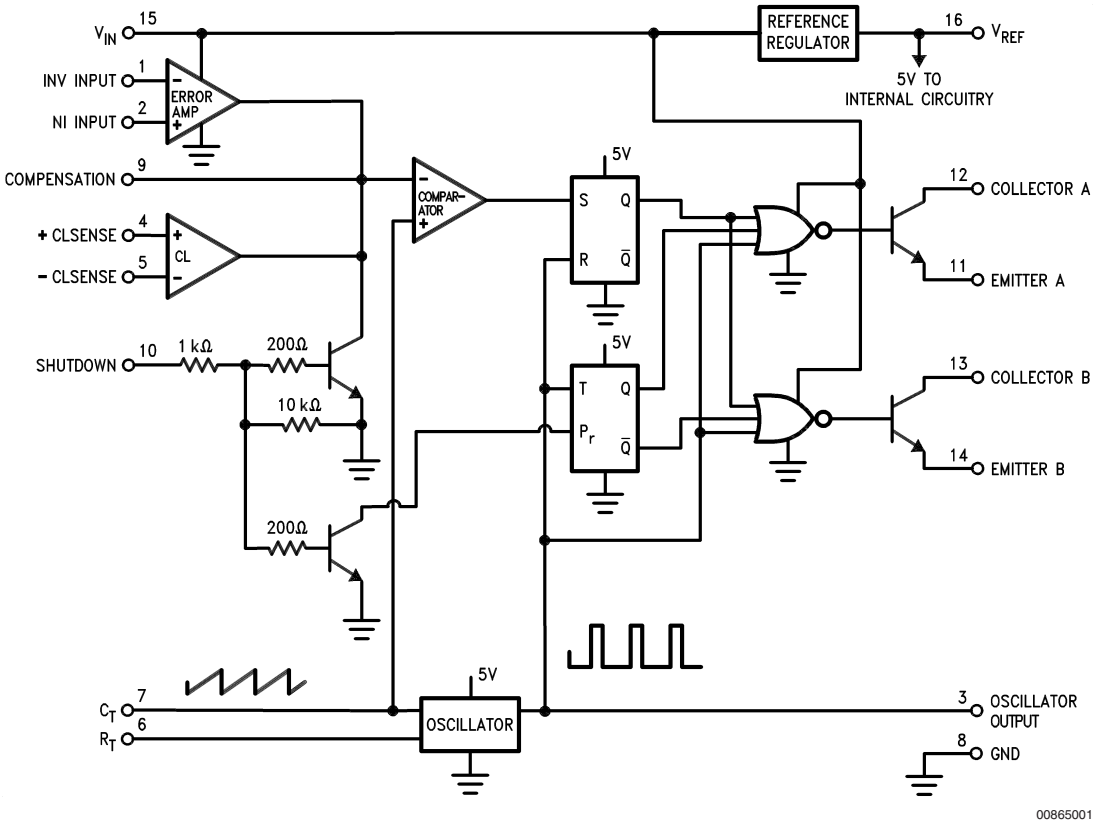
- Fully interchangeable with standard LM3524 family
- ±1% precision 5V reference with thermal shut-down
- Output current to 200 mA DC
- 60V output capability
- Wide common mode input range for error-amp
- One pulse per period (noise suppression)
- Improved max. duty cycle at high frequencies
- Double pulse suppression
- Synchronize through pin 3

Connection Diagram



Top View
Order Number LM2524DN or LM3524DN
See NS Package Number N16E
Order Number LM3524DM
See NS Package Number M16A

Block Diagram



Absolute Maximum Ratings (Note 5)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage	40V
Collector Supply Voltage	
(LM2524D)	55V
(LM3524D)	40V
Output Current DC (each)	200 mA
Oscillator Charging Current (Pin 7)	5 mA
Internal Power Dissipation	1W
Operating Junction Temperature Range (Note 2)	
LM2524D	−40˚C to +125˚C
LM3524D	0˚C to +125˚C
Maximum Junction Temperature	150˚
Storage Temperature Range	−65˚C to +150˚C
Lead Temperature (Soldering 4 sec.)	
M, N Pkg.	260˚C

Electrical Characteristics

(Note 1)

Symbol	Parameter	Conditions	LM2524D			LM3524D			Units
			Typ	Tested Limit (Note 3)	Design Limit (Note 4)	Typ	Tested Limit (Note 3)	Design Limit (Note 4)	
REFERENCE SECTION									
V_{REF}	Output Voltage		5	4.85	**4.80**	5	4.75		V_{Min}
				5.15	**5.20**		5.25		V_{Max}
V_{RLine}	Line Regulation	V_{IN} = 8V to 40V	10	15	**30**	10	25	50	mV_{Max}
V_{RLoad}	Load Regulation	I_L = 0 mA to 20 mA	10	15	**25**	10	25	50	mV_{Max}
$\frac{\Delta V_{IN}}{\Delta V_{REF}}$	Ripple Rejection	f = 120 Hz	66			66			dB
I_{OS}	Short Circuit Current	V_{REF} = 0		25			25		mA Min
			50			50			
				180			200		mA Max
N_O	Output Noise	10 Hz ≤ f ≤ 10 kHz	40		100	40		100	$\mu V_{rms\ Max}$
	Long Term Stability	T_A = 125˚C	20			20			mV/kHr
OSCILLATOR SECTION									
f_{OSC}	Max. Freq.	R_T = 1k, C_T = 0.001 µF (Note 7)	550		500	350			kHz_{Min}
f_{OSC}	Initial Accuracy	R_T = 5.6k, C_T = 0.01 µF (Note 7)		17.5			17.5		kHz_{Min}
			20			20			
				22.5			22.5		kHz_{Max}
		R_T = 2.7k, C_T = 0.01 µF (Note 7)		34			30		kHz_{Min}
			38			38			
				42			46		kHz_{Max}
Δf_{OSC}	Freq. Change with V_{IN}	V_{IN} = 8 to 40V	0.5	1		0.5	1.0		$\%_{Max}$
Δf_{OSC}	Freq. Change with Temp.	T_A = −55˚C to +125˚C at 20 kHz R_T = 5.6k, C_T = 0.01 µF	5			5			%
V_{OSC}	Output Amplitude (Pin 3) (Note 8)	R_T = 5.6k, C_T = 0.01 µF	3	2.4		3	2.4		V_{Min}
t_{PW}	Output Pulse Width (Pin 3)	R_T = 5.6k, C_T = 0.01 µF	0.5	1.5		0.5	1.5		μs_{Max}
	Sawtooth Peak Voltage	R_T = 5.6k, C_T = 0.01 µF	3.4	3.6	**3.8**		3.8		V_{Max}

Electrical Characteristics (Continued)

(Note 1)

Symbol	Parameter	Conditions	LM2524D			LM3524D			Units
			Typ	Tested Limit (Note 3)	Design Limit (Note 4)	Typ	Tested Limit (Note 3)	Design Limit (Note 4)	
	Sawtooth Valley Voltage	R_T = 5.6k, C_T = 0.01 µF	1.1	0.8	**0.6**		0.6		V_{Min}
ERROR-AMP SECTION									
V_{IO}	Input Offset Voltage	V_{CM} = 2.5V	2	8	**10**	2	10		mV_{Max}
I_{IB}	Input Bias Current	V_{CM} = 2.5V	1	8	**10**	1	10		μA_{Max}
I_{IO}	Input Offset Current	V_{CM} = 2.5V	0.5	1.0	**1**	0.5	1		μA_{Max}
I_{COSI}	Compensation Current (Sink)	$V_{IN(I)} - V_{IN(NI)}$ = 150 mV	95	65 125		95	65 125		μA_{Min} μA_{Max}
I_{COSO}	Compensation Current (Source)	$V_{IN(NI)} - V_{IN(I)}$ = 150 mV	–95	–125 –65		–95	–125 –65		μA_{Min} μA_{Max}
A_{VOL}	Open Loop Gain	$R_L = \infty$, V_{CM} = 2.5 V	80	74	**60**	80	70	60	dB_{Min}
VCMR	Common Mode Input Voltage Range			1.5 5.5	**1.4** **5.4**		1.5 5.5		V_{Min} V_{Max}
CMRR	Common Mode Rejection Ratio		90	80		90	80		dB_{Min}
G_{BW}	Unity Gain Bandwidth	A_{VOL} = 0 dB, V_{CM} = 2.5V	3			2			MHz
V_O	Output Voltage Swing	$R_L = \infty$		0.5 5.5			0.5 5.5		V_{Min} V_{Max}
PSRR	Power Supply Rejection Ratio	V_{IN} = 8 to 40V	80		70	80	65		db_{Min}
COMPARATOR SECTION									
$\frac{t_{ON}}{t_{OSC}}$	Minimum Duty Cycle	Pin 9 = 0.8V, [R_T = 5.6k, C_T = 0.01 µF]	0	0		0	0		$\%_{Max}$
$\frac{t_{ON}}{t_{OSC}}$	Maximum Duty Cycle	Pin 9 = 3.9V, [R_T = 5.6k, C_T = 0.01 µF]	49	45		49	45		$\%_{Min}$
$\frac{t_{ON}}{t_{OSC}}$	Maximum Duty Cycle	Pin 9 = 3.9V, [R_T = 1k, C_T = 0.001 µF]	44	35		44	35		$\%_{Min}$
V_{COMPZ}	Input Threshold (Pin 9)	Zero Duty Cycle	1			1			V
V_{COMPM}	Input Threshold (Pin 9)	Maximum Duty Cycle	3.5			3.5			V
I_{IB}	Input Bias Current		–1			–1			µA
CURRENT LIMIT SECTION									
V_{SEN}	Sense Voltage	$V_{(Pin\ 2)} - V_{(Pin\ 1)} \geq$ 150 mV	200	180 220		200	180 220		mV_{Min} mV_{Max}

Electrical Characteristics (Continued)

(Note 1)

Symbol	Parameter	Conditions	LM2524D			LM3524D			Units
			Typ	Tested Limit (Note 3)	Design Limit (Note 4)	Typ	Tested Limit (Note 3)	Design Limit (Note 4)	
TC-V_{sense}	Sense Voltage T.C.		0.2			0.2			mV/˚C
	Common Mode Voltage Range	$V_5 - V_4$ = 300 mV	–0.7 1			–0.7 1			V_{Min} V_{Max}
SHUT DOWN SECTION									
V_{SD}	High Input Voltage	$V_{(Pin\ 2)} - V_{(Pin\ 1)} \geq$ 150 mV	1	0.5 1.5		1	0.5 1.5		V_{Min} V_{Max}
I_{SD}	High Input Current	$I_{(pin\ 10)}$	1			1			mA
OUTPUT SECTION (EACH OUTPUT)									
V_{CES}	Collector Emitter Voltage Breakdown	$I_C \leq$ 100 µA		55			40		V_{Min}
I_{CES}	Collector Leakage Current	V_{CE} = 60V							
		V_{CE} = 55V	0.1	50					μA_{Max}
		V_{CE} = 40V				0.1	50		
V_{CESAT}	Saturation Voltage	I_E = 20 mA	0.2	0.5		0.2	0.7		V_{Max}
		I_E = 200 mA	1.5	2.2		1.5	2.5		
V_{EO}	Emitter Output Voltage	I_E = 50 mA	18	17		18	17		V_{Min}
t_R	Rise Time	V_{IN} = 20V, I_E = –250 µA R_C = 2k	200			200			ns
t_F	Fall Time	R_C = 2k	100			100			ns
SUPPLY CHARACTERISTICS SECTION									
V_{IN}	Input Voltage Range	After Turn-on		8 40			8 40		V_{Min} V_{Max}
T	Thermal Shutdown Temp.	(Note 2)	160			160			˚C
I_{IN}	Stand By Current	V_{IN} = 40V (Note 6)	5	10		5	10		mA

Note 1: Unless otherwise stated, these specifications apply for $T_A = T_J = 25˚C$. Boldface numbers apply over the rated temperature range: LM2524D is –40˚ to 85˚C and LM3524D is 0˚C to 70˚C. V_{IN} = 20V and f_{OSC} = 20 kHz.

Note 2: For operation at elevated temperatures, devices in the N package must be derated based on a thermal resistance of 86˚C/W, junction to ambient. Devices in the M package must be derated at 125˚C/W, junction to ambient.

Note 3: Tested limits are guaranteed and 100% tested in production.

Note 4: Design limits are guaranteed (but not 100% production tested) over the indicated temperature and supply voltage range. These limits are not used to calculate outgoing quality level.

Note 5: Absolute maximum ratings indicate limits beyond which damage to the device may occur. DC and AC electrical specifications do not apply when operating the device beyond its rated operating conditions.

Note 6: Pins 1, 4, 7, 8, 11, and 14 are grounded; Pin 2 = 2V. All other inputs and outputs open.

Note 7: The value of a C_t capacitor can vary with frequency. Careful selection of this capacitor must be made for high frequency operation. Polystyrene was used in this test. NPO ceramic or polypropylene can also be used.

Note 8: OSC amplitude is measured open circuit. Available current is limited to 1 mA so care must be exercised to limit capacitive loading of fast pulses.